R **ICHX**

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- Productor Character
- Multilayer Metal -Silicon Potential Structure.
- Low Leakage Current.
- High Current Capability, High Efficiency.
- High Junction Temperature Capability.
- RoHS Product.
- Compliance with EU REACH.

Summarize

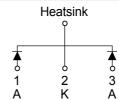
 EBR40L100CT Device optimized for ultra-low forward voltage drop to maximize efficiency in Power Supply applications.

Primary Use

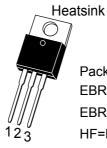
 Low Voltage High Frequency Switching Power Supply.

- Low Voltage High Frequency Invers Circuit.
- Low Voltage Continued Circuit and Protection Circuit.

Equivalent Circuit







Package:TO-220AB EBR40L100CT EBR40L100CT-HF **HF=Halogen Free**

Absolute Maximum Ratings(Ta=25°C unless otherwise noted)

ltem		Symbol	Data	Unit
Maximal Inverted Repetitive Peak Voltage		V _{RRM}	100	V
Average Rectified Forward Current(Rated VR-	Per Device	- I _{FAV}	40	A
20Khz Square Wave)-50% duty cycle	Per Diode		20	
Forward Peak Surge Current(Rated Load 8.3 Half Mssine Wave-According to JEDEC Method	d) Per Diode	I _{FSM}	270	А
Operating Junction Temperature		TJ	-40~150	°C
Storage Temperature		T _{STG}	-40~150	°C
Typical Thermal Resistance(per leg) Package	e=TO-220AB	$R_{ extsf{ heta}JC}$	2	°C/W

Electricity Character Per Diode(Ta=25°C unless otherwise noted)

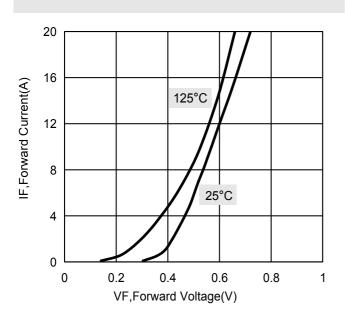
ltem	Test Condition	Value(min)	Value(typ)	Value(max)	Unit
V _B	Tj=25°C,IR=1mA	100	_	_	V
۱ _R	Tj=25°C,VR=100V	—	—	30	μA
	Tj=100°C,VR=100V	—	—	10	mA
V _F	Tj=25°C,IF=20A	—	0.72	0.82	V
	Tj=125°C,IF=20A	—	—	0.75	V
CJ	Tj=25°C,VR=4V,f=1MHz	—	1195	—	pF





Typical Characteristics Curves

Fig1.Typical Forward Current and Forward Voltage



50 40 30

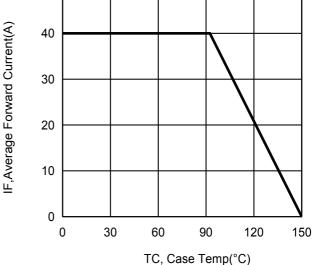


Fig2.Typical Current Derating Curve, Perelement

Fig3.Typical Reverse Current and Reverse Voltage

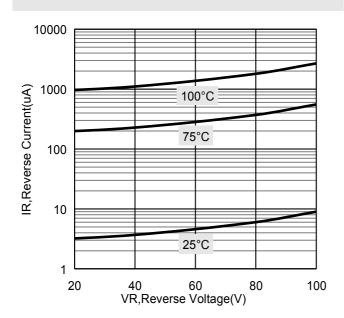
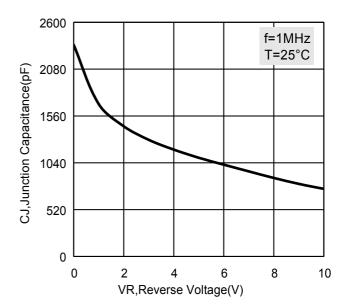


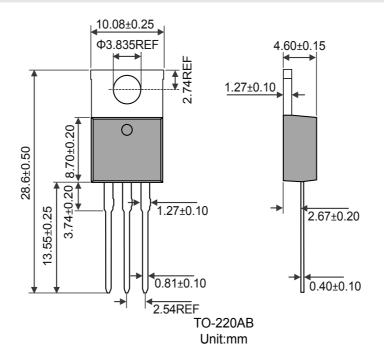
Fig4.Typical Junction Capacitance and Reverse Voltage







Package Outline Dimensions



Marking Information



"MHCHXM"= Product Logo "Marking Code"= The Following "XXXX"= Date Code Marking

Marking Code	Part Number	
EBR40L100	EBR40L100CT	
	EBR40L100CT-HF	



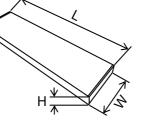
R HCHXN www.jshxm.com

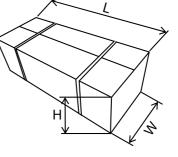
Packing Information

Packaging	Part Number	Quantity(pcs)	Size(mm)	
Tube	Tube	50	L534×W33×H7	
	Inner Box	1000	L560×W150×H40	
	Outer Box	5000	L570×W235×H175	

Packaging:Tube







Tube

Tube Inner Box

Tube Outer Box

Notes

Lead Forming

1.During lead frame bending, the lead frame should be bent at a distance more than 3mm from bottom of the epoxy.And the bending degree should not exceed 90°.

Note: The lead frame must be secured and do not touch the epoxy before bending to avoid damage to the transistor. In addition, when using a mold for a large number of lead molding, the structure of the fixed lead must be set, and it should be noted that the lead pressure rod structure cannot exert pressure on the epoxy resin body.

2. Do not bend the lead repeatedly. Do not bend the lead outward





Heat sink mounting

For power devices, in order to reduce junction temperature, heat dissipation blocks are usually used to disperse heat to the outside, and semiconductor power devices installed on the heat dissipation blocks can effectively dissipate heat without losing the reliability of the semiconductor, so the following matters should be noted when using:

1. Pay attention to the selection of silicone cream

In order to improve the thermal conductivity and heat dissipation effect of the device and the heat dissipation block, generally apply a thin layer of silicone grease evenly on the contact surface of the device and the heat dissipation block. Choose a silicone grease with low oil separation degree. Do not overapply it, otherwise it will attach too much stress to the resin.

2. Optimum torque is required

When using the fastening torque, pay attention not to use too much torque, so as not to damage the epoxy resin body, pay attention to the smooth cooling block body, no file chips and other foreign bodies between the transistor and the cooling block, pay attention to the selection of screws, nuts, gaskets and washers, so as not to cause damage to the transistor due to improper selection.

Soldering

1. Pay special attention to welding. When welding, the distance between the solder joint and the epoxy ball should be greater than 3mm, and it is recommended to weld it outside the tie rod base.

2. Avoid applying any pressure to the lead frame while the transistor is at high temperatures, especially when welding. Dip welding and manual welding should not be done more than once

Notes:

For specific precautions, please refer to our company's relevant technical documents or visit our official website at http://www.jshxm.com





DISCLAIMER

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2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.

3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. MHCHXM assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

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